## NSN 5961-01-381-9197

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-381-9197 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** Between 0.034 inches and 0.047 inches **Overall Width:** Between 0.047 inches and 0.055 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** This device has dummy treminal for mounting purposes; junction pattern arrangement: pin **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: